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[Vishay Semiconductor/Diodes Division](#)
[VS-113CNQ100APBF](#)

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sales@integrated-circuit.com



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VS-113CNQ100APbF Series

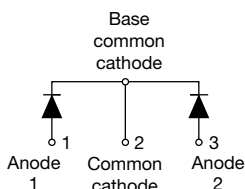
Vishay Semiconductors

High Performance Schottky Rectifier New Generation 3 D-61 Package, 2 x 55 A

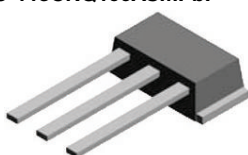
VS-113CNQ100APbF



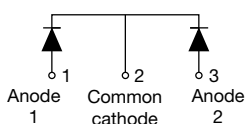
D-61-8



VS-113CNQ100ASMPbF



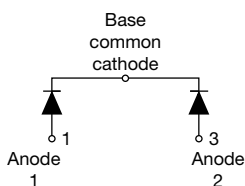
D-61-8-SM



VS-113CNQ100ASLPbF



D-61-8-SL



FEATURES

- 175 °C T_J operation
- Center tap module
- Low forward voltage drop
- High frequency operation
- High power discrete
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Guard ring for enhanced ruggedness and long term reliability
- New fully transfer-mold low profile, small footprint, high current package
- Designed and qualified for industrial level
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912



Available
RoHS*
Available

Note

* This datasheet provides information about parts that are RoHS-compliant and/or parts that are non-RoHS-compliant. For example, parts with lead (Pb) terminations are not RoHS-compliant. Please see the information/tables in this datasheet for details.

DESCRIPTION

The center tap Schottky rectifier module series has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

PRODUCT SUMMARY

Package	D-61-8, D-61-8-SM, D-61-8-SL
$I_{F(AV)}$	2 x 55 A
V_R	100 V
V_F at I_F	0.81 V
I_{RM} max.	32 mA at 125 °C
T_J max.	175 °C
Diode variation	Common cathode
E_{AS}	15 mJ

MAJOR RATINGS AND CHARACTERISTICS

SYMBOL	CHARACTERISTICS	VALUES	UNITS
$I_{F(AV)}$	Rectangular waveform	110	A
V_{RRM}		100	V
I_{FSM}	$t_p = 5 \mu s$ sine	7000	A
V_F	55 A _{pk} , $T_J = 125$ °C (per leg)	0.66	V
T_J	Range	-55 to +175	°C

VOLTAGE RATINGS

PARAMETER	SYMBOL	VS-113CNQ100APbF	UNITS
Maximum DC reverse voltage	V_R	100	V
Maximum working peak reverse voltage	V_{RWM}		


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ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS	
Maximum average forward current See fig. 5	per leg	$I_{F(AV)}$	50 % duty cycle at $T_C = 150\text{ }^\circ\text{C}$, rectangular waveform		55	A
	per device				110	
Maximum peak one cycle non-repetitive surge current per leg See fig. 7		I_{FSM}	5 μs sine or 3 μs rect. pulse	Following any rated load condition and with rated V_{RRM} applied	7000	A
			10 ms sine or 6 ms rect. pulse		720	
Non-repetitive avalanche energy per leg	E_{AS}	$T_J = 25\text{ }^\circ\text{C}$, $I_{AS} = 1\text{ A}$, $L = 30\text{ mH}$		15	mJ	
Repetitive avalanche current per leg	I_{AR}	Current decaying linearly to zero in 1 μs Frequency limited by T_J maximum $V_A = 1.5 \times V_R$ typical		1	A	

ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum forward voltage drop per leg See fig. 1	$V_{FM}^{(1)}$	55 A	$T_J = 25\text{ }^\circ\text{C}$	0.81	V
		110 A		1.00	
		55 A	$T_J = 125\text{ }^\circ\text{C}$	0.66	
		110 A		0.79	
Maximum reverse leakage current per leg See fig. 2	$I_{RM}^{(1)}$	$T_J = 25\text{ }^\circ\text{C}$	$V_R = \text{Rated } V_R$	1.0	mA
		$T_J = 125\text{ }^\circ\text{C}$		32	
Maximum junction capacitance per leg	C_T	$V_R = 5\text{ }V_{DC}$ (test signal range 100 kHz to 1 MHz), $25\text{ }^\circ\text{C}$		1960	pF
Typical series inductance per leg	L_S	Measured lead to lead 5 mm from package body		5.5	nH
Maximum voltage rate of change	dV/dt	Rated V_R		10 000	V/ μs

Note

 (1) Pulse width < 300 μs , duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum junction and storage temperature range	T_J, T_{Stg}			-55 to +175	$^\circ\text{C}$
Maximum thermal resistance, junction to case per leg	R_{thJC}	DC operation See fig. 4		0.5	$^\circ\text{C}/\text{W}$
Maximum thermal resistance, junction to case per package		DC operation		0.25	
Typical thermal resistance, case to heatsink (D-61-8 only)	R_{thCS}	Mounting surface, smooth and greased Device flatness < 5 mils		0.30	
Approximate weight				7.8	g
				0.28	oz.
Mounting torque (D-61-8 only)	minimum	Recommended hardware 3M stainless screw		12 (10)	kgf · cm (lbf · in)
	maximum			24 (20)	
Marking device		Case style D-61-8		113CNQ100A	
		Case style D-61-8-SM		113CNQ100ASM	
		Case style D-61-8-SL		113CNQ100ASL	



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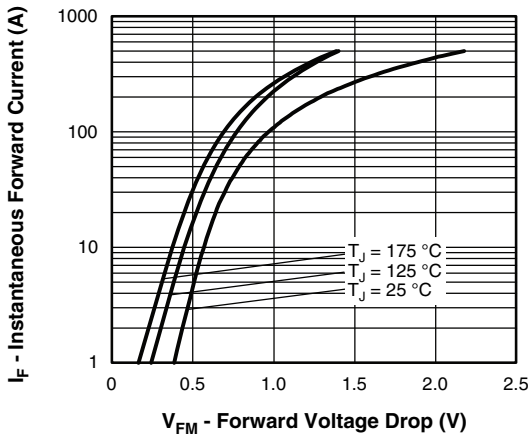


Fig. 1 - Maximum Forward Voltage Drop Characteristics (Per Leg)

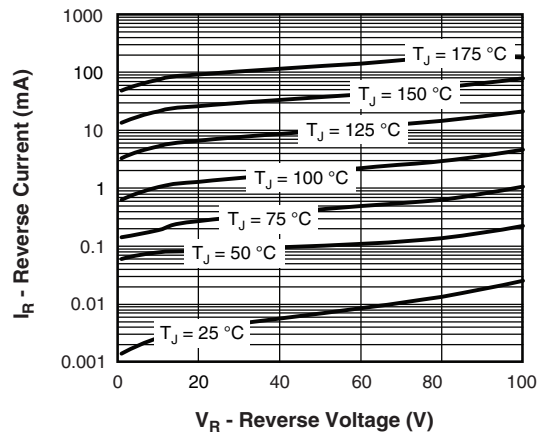


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage (Per Leg)

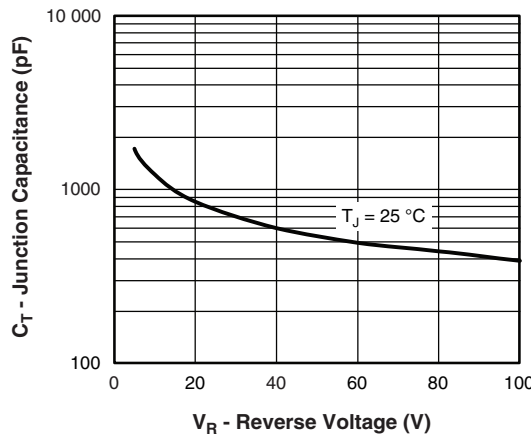


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

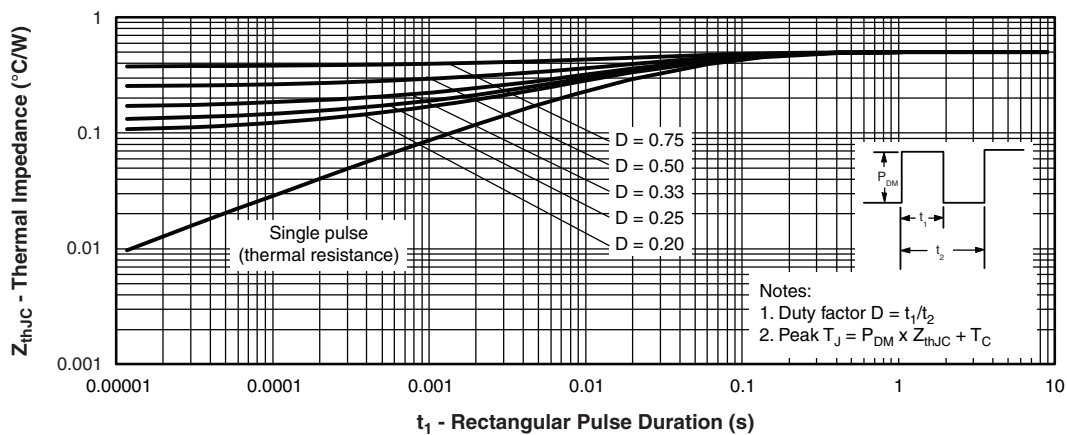


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics (Per Leg)



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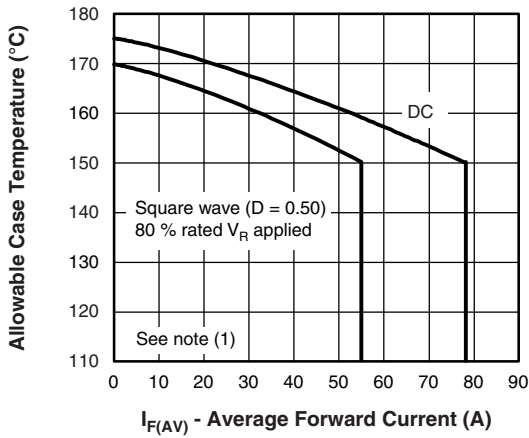


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current (Per Leg)

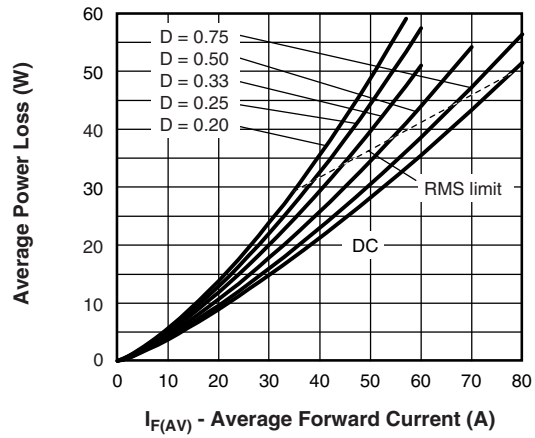


Fig. 6 - Forward Power Loss Characteristics (Per Leg)

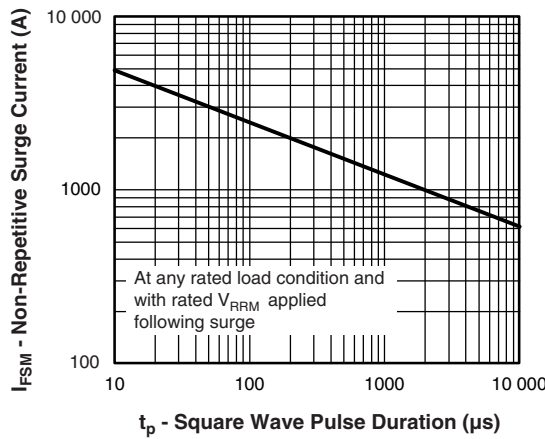


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

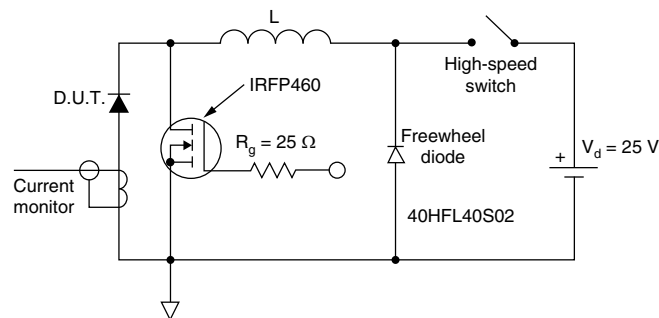


Fig. 8 - Unclamped Inductive Test Circuit

Note

- (1) Formula used: $T_C = T_J - (P_d + P_{d_{REV}}) \times R_{thJC}$;
- P_d = Forward power loss = $I_{F(AV)} \times V_{FM}$ at $(I_{F(AV)}/D)$ (see fig. 6);
- $P_{d_{REV}}$ = Inverse power loss = $V_{R1} \times I_R (1 - D)$; I_R at $V_{R1} = 80\%$ rated V_R



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VS-113CNQ100APbF Series

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ORDERING INFORMATION TABLE

Device code	VS-	113	C	N	Q	100	A	PbF
	①	②	③	④	⑤	⑥	⑦	⑧

- 1** - Vishay Semiconductors product
- 2** - Current rating (110 A)
- 3** - Circuit configuration:
C = common cathode
- 4** - Package:
N = D-61
- 5** - Schottky "Q" series
- 6** - Voltage rating (100 = 100 V)
- 7** - Package style:
 - A = D-61-8
 - ASM = D-61-8-SM
 - ASL = D-61-8-SL
- 8** -
 - None = standard production
 - PbF = lead (Pb)-free

Standard pack quantity: A = 10 pieces; ASM/ASL = 20 pieces

LINKS TO RELATED DOCUMENTS	
Dimensions	www.vishay.com/doc?95354
Part marking information	www.vishay.com/doc?95356



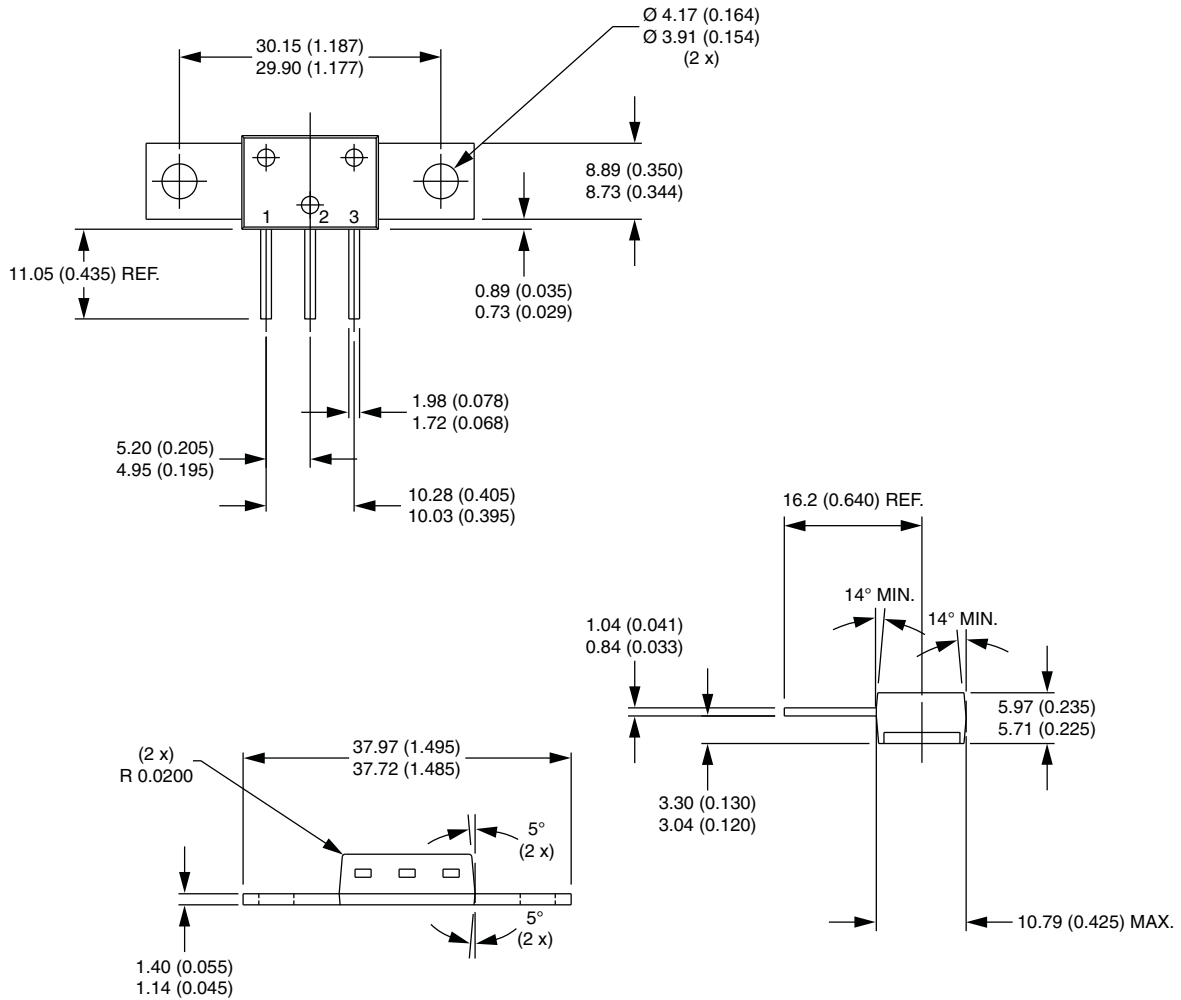
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Outline Dimensions

Vishay Semiconductors

D-61-8, D-61-8-SM, D-61-8-SL

DIMENSIONS - D-61-8 in millimeters (inches)



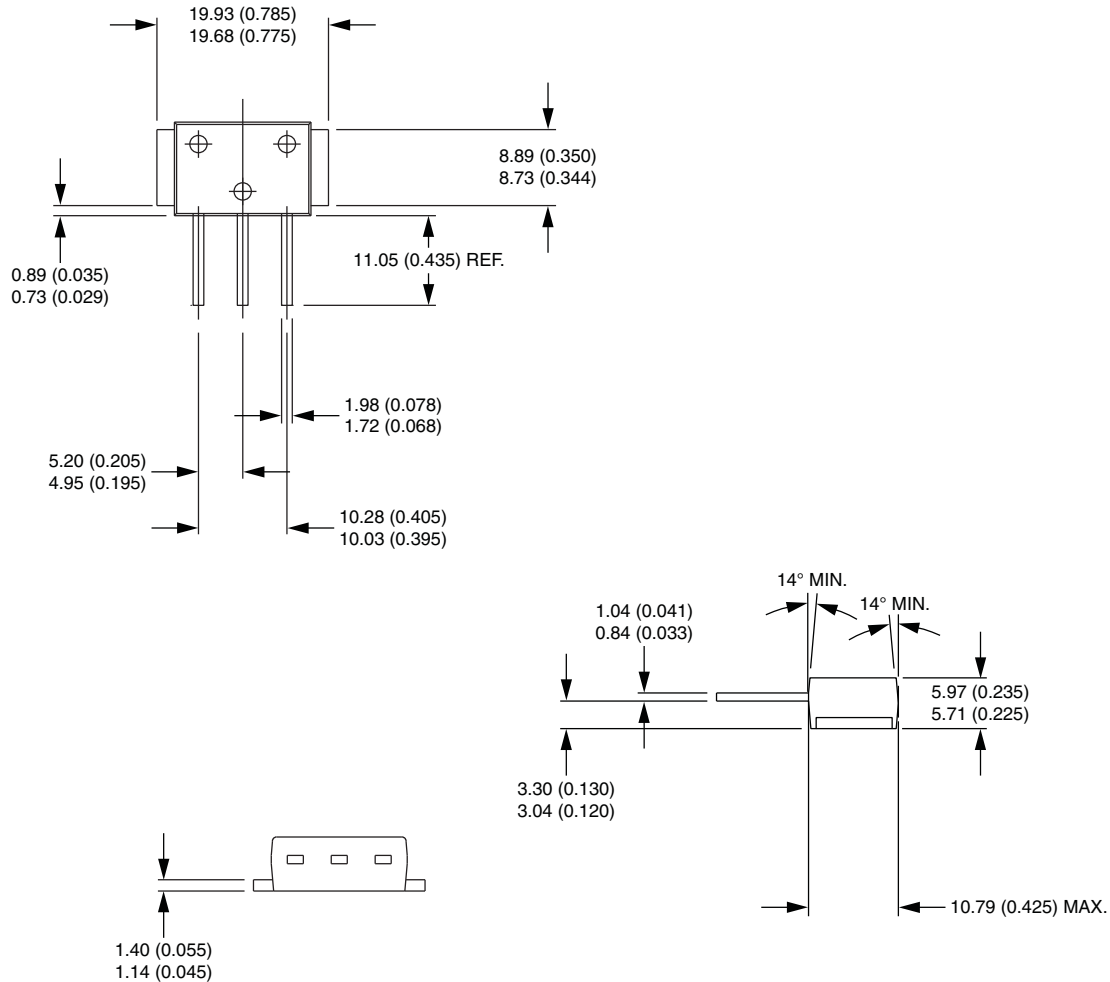


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Outline Dimensions

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DIMENSIONS - D-61-8-SM in millimeters (inches)



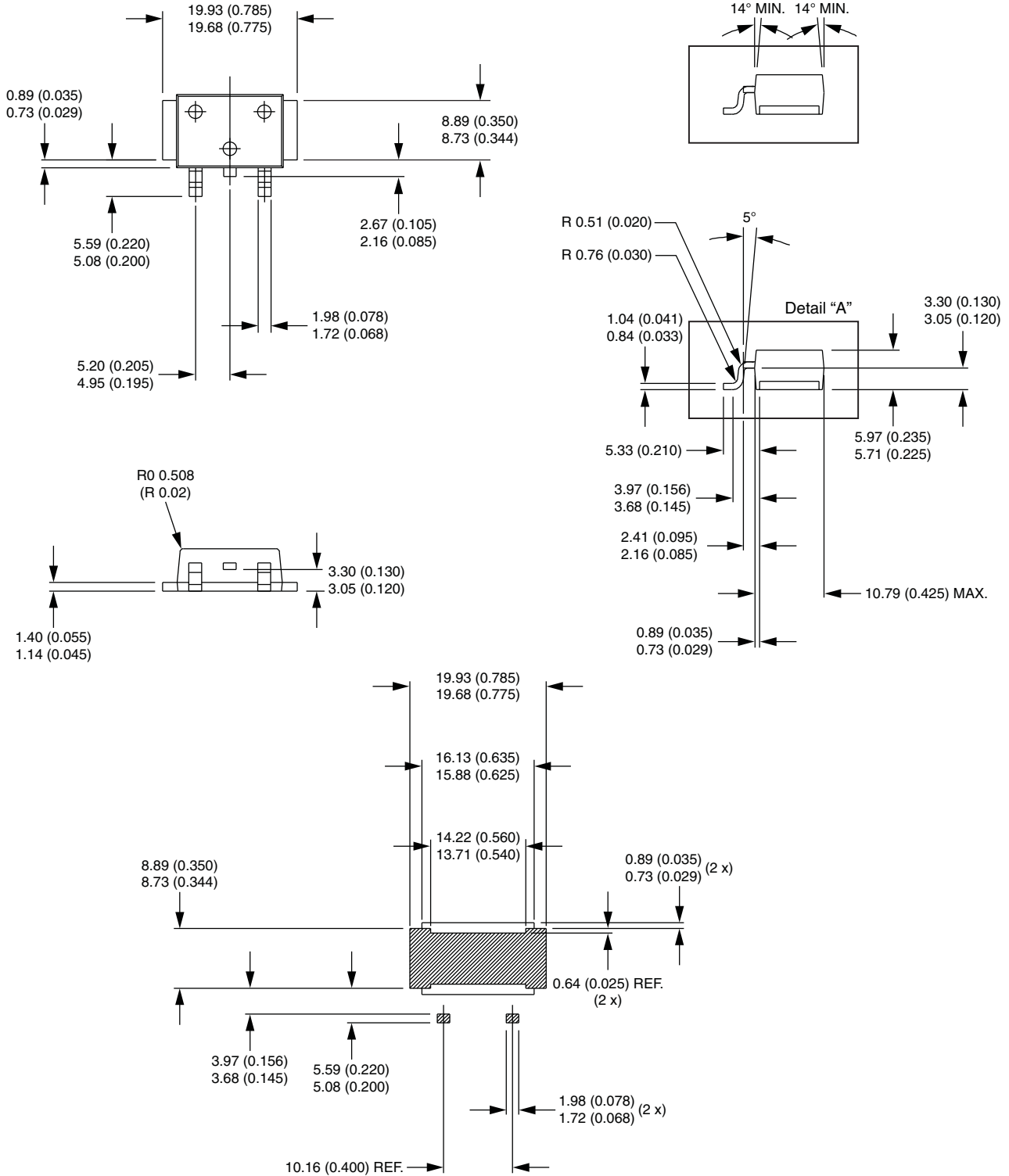


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Outline Dimensions

Vishay Semiconductors

DIMENSIONS - D-61-8-SL in millimeters (inches)





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